# imall

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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

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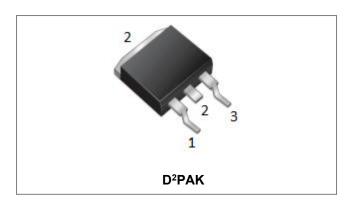


## MBRB2060CT

Technical Data Data Sheet N0118, Rev. B



## **MBRB2060CT SCHOTTKY RECTIFIER**



#### Features

- 150°C TJ operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

## Maximum Ratings:

**Circuit Diagram** 

Base common Cathode

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	60	V
Average Rectified Forward Current (Per Device)	IF (AV)	50% duty cycle @Tc=80°C, rectangular wave form	10(Per Leg) 20(Per Device)	A
RMS Forward Current	I <sub>F(RMS)</sub>	-	22.2	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	IFSM	8.3ms, Half Sine pulse	150	А

### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V <sub>F1</sub>	@ 10A, Pulse, T <sub>J</sub> = 25 °C	0.74	0.80	V
(Per Leg) *	V <sub>F2</sub>	@ 10A, Pulse, T <sub>J</sub> = 125 °C	0.63	0.70	V
Reverse Current (Per Leg) *	I <sub>R1</sub>	$@V_R = rated V_{R,} T_J = 25 \circ C$	0.02	1	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 125 °C	9	50	mA
Junction Capacitance(Per Leg)	Ст	$@V_{R} = 5V, T_{C} = 25 \ ^{\circ}C, f_{SIG} = 1MHz$	180	400	pF
Series Inductance(Per Leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

Pulse width < 300  $\mu$ s, duty cycle < 2%

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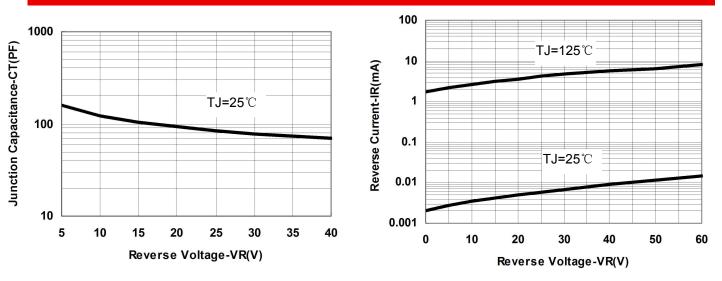
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RoHS 🗭

### **Thermal-Mechanical Specifications:**

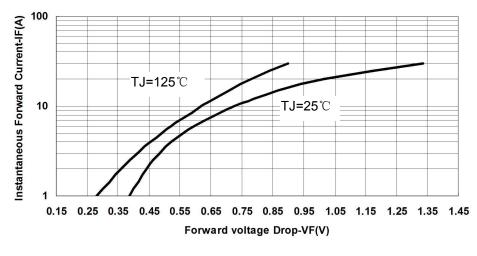
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	Rejc	DC operation	2.3	°C/W
Approximate Weight	wt	-	1.85	g
Case Style	D <sup>2</sup> PAK			

## **Ratings and Characteristics Curves**



#### **Fig.1-Typical Junction Capacitance**

**Fig.2-Typical Reverse Characteristics** 





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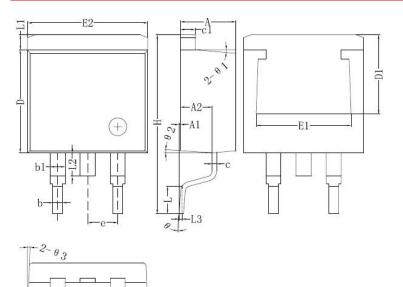


## MBRB2060CT

## RoHS

#### **Technical Data** Data Sheet N0118, Rev. B

## Mechanical Dimensions D<sup>2</sup>PAK



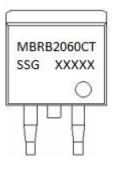
Symbol	Dimensions in millimet		
	Min.	Typical	Max.
A	4.47	4.70	4.85
A1	0	0.10	0.25
A2	2.59	2.69	2.89
b	0.71	0.81	0.96
b1	1.17	1.27	1.37
С	0.31	0.38	0.61
c1	1.17	1.27	1.37
D	8.50	8.70	8.90
D1	6.40		
E	10.01	10.16	10.31
E1	7.6		
E2	9.98	10.08	10.31
е		2.54	
Н	14.6	15.1	15.6
L	2.00	2.30	2.74
L1	1.12	1.27	1.42
L2	1.30		2.20
L3		0.25BSC	
е	0	-	8°
e1		5°	
e2		<b>4</b> °	
e3		<b>4</b> °	

## **Ordering Information**

Device	Package	Shipping
MBRB2060CT	D <sup>2</sup> PAK	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**



#### Where XXXXX is YYWWL

В 20

60

CT SSG

YY WW

L

MBR = Device Type

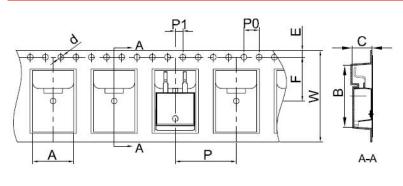
- = Device Type = Package type = Forward Current (20A) = Reverse Voltage(60V)

= Configuration = SSG

- = Year
- = Week
- = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

## Carrier Tape Specification D<sup>2</sup>PAK



SYMBOL	Millimeters		
STWIDUL	Min.	Max.	
A	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

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## MBRB2060CT



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